Unitized Semiconductor Devices - Page 1 of 1



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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.150 inches and 0.185 inches

## **Terminal Length:**

0.500 inches

### **Overall Diameter:**

Between 0.335 inches and 0.370 inches

### **Component Name And Quantity:**

2 transistor

### **Mounting Method:**

Terminal

**Terminal Circle Diameter:** 

0.200 inches

### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon all transistor

### Voltage Rating In Volts Per Characteristic:

30.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage, dc all transistor and 3.0 emitter to base voltage, dc all transistor

### **Current Rating Per Characteristic:**

50.00 milliamperes source cutoff current all transistor

### **Power Rating Per Characteristic:**

600.0 milliwatts small-signal input power, common-collector preset all transistor

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

All transistor junction pattern arrangement: npn

### **Terminal Type And Quantity:**

6 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

No

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